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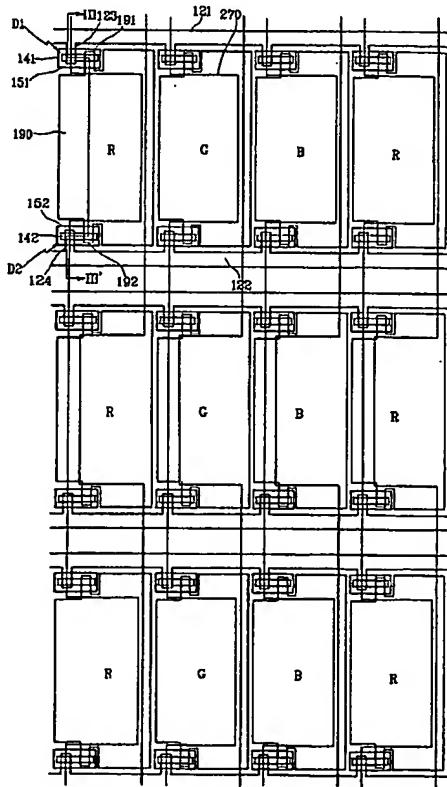
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(54) Title: LIQUID CRYSTAL DISPLAY OF USING DUAL SELECT DIODE



(57) Abstract: A liquid crystal display comprising: a first insulating substrate; first and second gate lines (121,122) formed on the first insulating substrate; a pixel electrode (190) formed on the first insulating substrate; a first MIM diode (D1) formed on the first insulating substrate connecting the first gate line (121) and the pixel electrode (190); a second MIM diode (D2) formed on the first insulating substrate connecting the second gate line (122) and the pixel electrode (190); a second insulating substrate (210) facing the first insulating substrate; and a data electrode line (270) formed on the second insulating substrate and intersecting the first and second gate lines (121,122), and wherein the data electrode line (270) includes protrusions toward right and left sides by turns to overlap a predetermined number of pixel electrodes (190) of the right and left sides by turns is provided.



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